

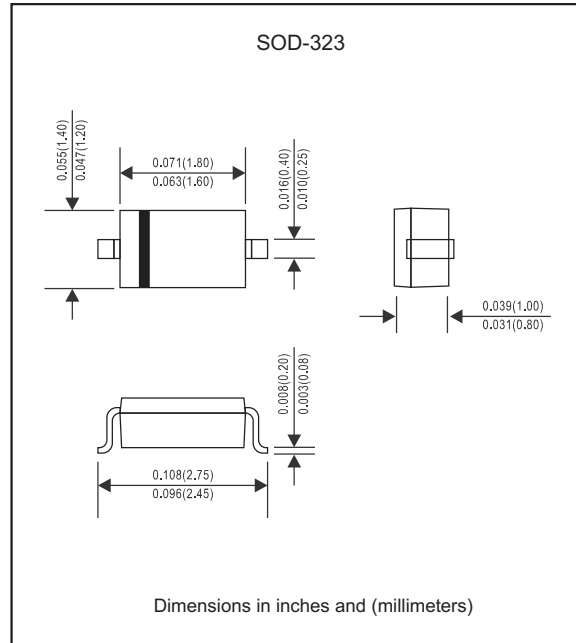
Features

- Low current rectification and high speed switching
- Small surface mount type
- Up to 200mA current capability
- Low forward voltage drop (0.35V typ. @ $I_F=10\text{mA}$)
Silicon epitaxial planar chip, metal silicon junction
- High speed ($t_{rr} < 6\text{ ns}$)
- Lead-free parts meet RoHS requirements
- Compliant to Halogen-free
- Suffix "-Q1" for AEC-Q101

Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- Case : Molded plastic, SOD-323
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity : Indicated by cathode band
- Mounting Position : Any

Package outline



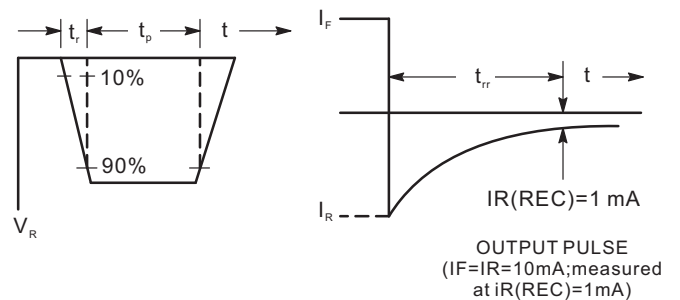
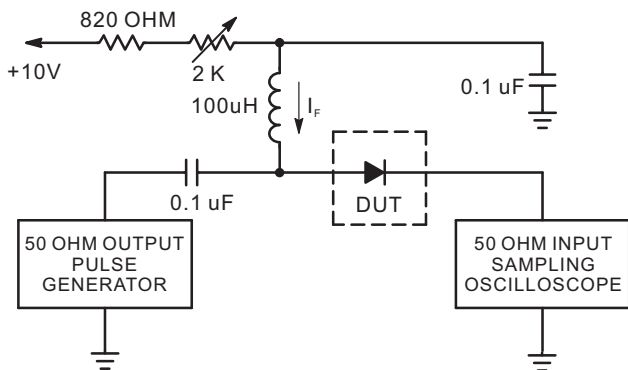
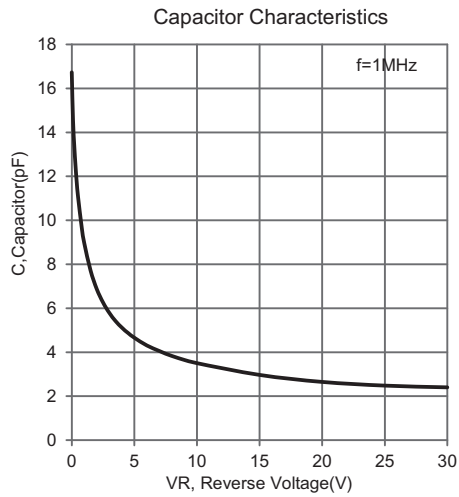
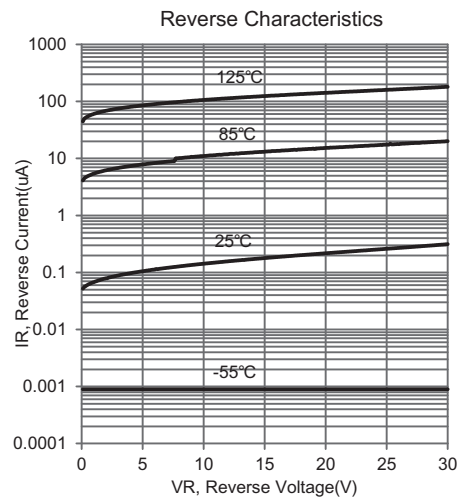
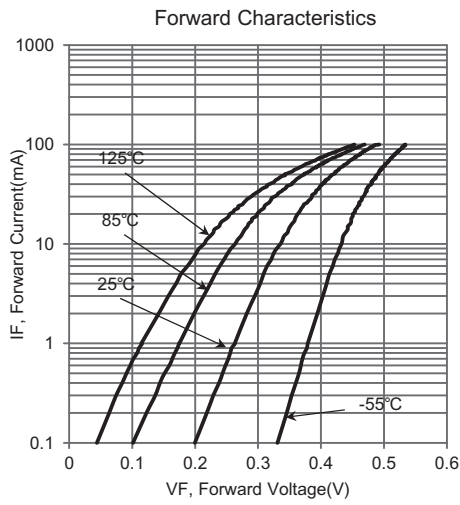
Maximum ratings (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Repetitive peak reverse voltage		V_{RRM}			30	V
Reverse voltage		V_R			30	V
Repetitive peak forward current		I_{FRM}			300	mA
Non-repetitive peak forward current	$t < 1.0\text{ s}$	I_{FSM}			600	mA
Forward current		I_F			200	mA
Power dissipation	Mounted on FR-5 board at $T_A=25^\circ\text{C}$	P_D			200	mW
Thermal resistance	Junction to ambient	$R_{\theta JA}$		635		$^\circ\text{C/W}$
Operating junction temperature range		T_J	-55		+125	$^\circ\text{C}$
Storage temperature range		T_{STG}	-55		+125	$^\circ\text{C}$

Electrical characteristics (AT $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 0.1\text{ mA}$	V_F		0.220	0.240	V
	$I_F = 1\text{ mA}$	V_F		0.290	0.320	V
	$I_F = 10\text{ mA}$	V_F		0.350	0.400	V
	$I_F = 30\text{ mA}$	V_F		0.410	0.500	V
	$I_F = 100\text{ mA}$	V_F		0.520	1.000	V
Reverse current	$V_R = 25\text{ V}$	I_R		0.5	2.0	μA
Total capacitance	$V_R = 1\text{ V}, f = 1\text{ MHz}$	C_T			10.0	pF
Reverse recovery time	$I_F = I_R = 10\text{ mA}, I_{R(REC)} = 1.0\text{ mA}$	t_{rr}			6.0	ns



Rating and characteristic curves (BAT54WS-Q1)



- Notes : 1. A2.0 Kohm variable resistor adjusted for a forward Current (I_F) of 10mA.
 2. Input pulse is adjusted so $I_R(\text{peak})$ is equal to 10 mA.
 3. $t_p \gg t_{rr}$.

Recovery Time Equivalent Test Circuit

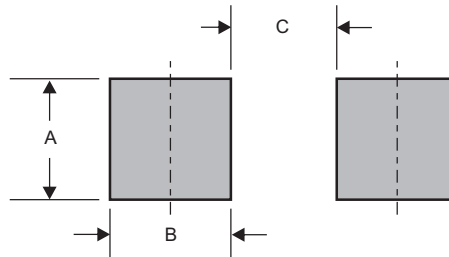
Pinning information

Pin	Simplified outline	Symbol
Pin1 cathode Pin2 anode		

Marking

Type number	Marking code
BAT54WS-Q1	L9 or S1

Suggested solder pad layout



Dimensions in inches and (millimeters)

PACKAGE	A	B	C
SOD-323	0.032 (0.82)	0.022 (0.56)	0.069 (1.75)